BAV19/BAV20/BAV21

Taiwan Semiconductor

200mA,120-250V Switching Diode

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

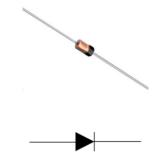
- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

- Case: DO-35
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Polarity: Indicated by cathode band
- Weight: 109 ± 4 mg (approximately)

KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I _{F(AV)}	100-200	mA			
V _{RRM}	120-250	V			
I _{FSM} at PW = 1µs	4	А			
V _F at I _F =100mA	1.00 V				
T _{J MAX}	175	°C			
Package	DO-35				
Configuration	Single Die				





ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		SYMBOL	PART NUMBER		UNIT	
Marking code on the device			BAV19	BAV20	BAV21	
Reverse Breakdown Voltage	IR = 100 μA	$V_{(BR)}$	120	200	250	V
Peak Forward Surge Current	Pulse Width = 1 s , Square Wave		1 4		A	
	Pulse Width = 1 µs , Square Wave	I _{FSM}				
Junction temperature range		T_J	-55 ~ 175		°C	
Storage temperature range		T _{STG}	-	55 ~ 17	5	°C

THERMAL PERFORMANCE					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-ambient thermal resistance	R _{eJA}	300	°C/W		



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ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT	
Forward voltage per diode (1)	I _F = 100mA, T _J = 25°C			1.00	V	
	$I_F = 200 \text{mA}, T_J = 25^{\circ}\text{C}$	V _F		1.25	V	
Reverse current @ rated V_R per diode $^{(2)}$	BAV19 VR = 100 V			100	nA	
	BAV20 VR = 150 V	I _R				
	BAV21 VR = 200 V					
Junction capacitance	1 MHz, V _R =0V	CJ		5	ρF	

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

ORDERING INFORMATION					
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING	
BAVXX (Note 1&2)	R0	G	DO-35	10K / 14" Reel	
	A0			5K / Box (Ammo)	

Notes:

"xx" is Device Code from "19" to "21" 1.

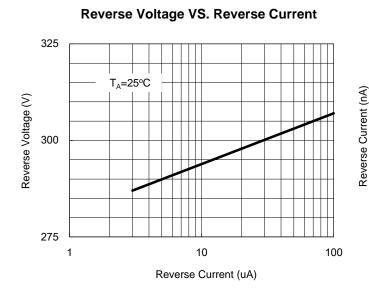
Whole series with green compound 2.

EXAMPLE						
EXAMPLE P/N PART NO. PACKING CODE		PACKING CODE SUFFIX	DESCRIPTION			
BAV19 R0G	BAV19	R0	G	Green compound		

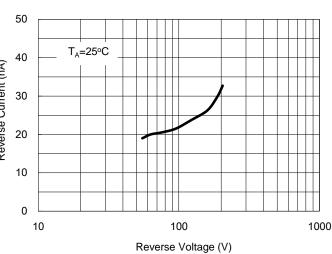


CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)



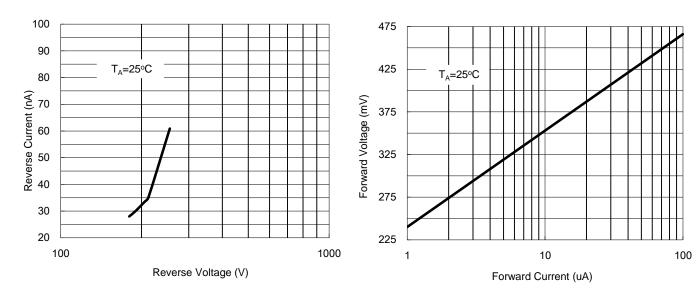
Reverse Current VS. Reverse Voltage



Reverse Current VS. Reverse Voltage



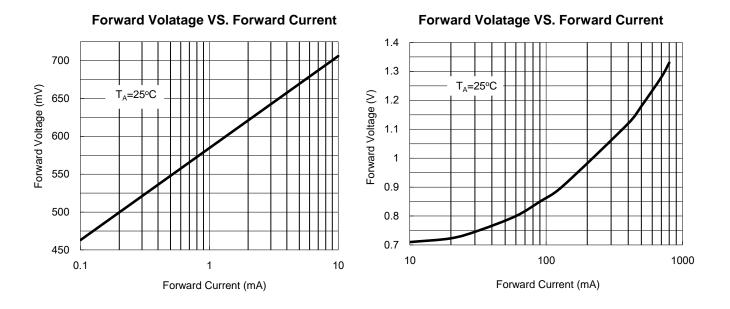
Forward Voltage VS. Forward Current





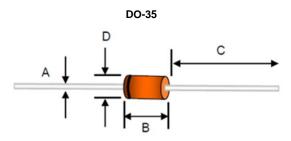
CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$





PACKAGE OUTLINE DIMENSION



DIM.	Unit(mm)		Unit(inch)		
DIN.	Min	Max	Min	Max	
A	0.34	0.60	0.013	0.024	
В	2.90	5.08	0.114	0.200	
С	25.40	38.10	1.000	1.500	
D	1.30	2.28	0.051	0.090	

MARKING DIAGRAM





BAV19/BAV20/BAV21

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